Influence of ZnO on Physical, Mechanical and Dielectric Properties of Ceramic Bodies

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ABSTRACT: Physical, mechanical and dielectric properties of ceramic bodies produced from the low-cost Egyptian raw materials with and without incorporation of ZnO were examined before and after annealing at different temperatures for different annealing times. The development of the crystalline phases was evaluated with x-ray diffraction (XRD). The dielectric properties in terms of the permittivity, dielectric loss and resistivity were investigated in the frequency range (10⁻¹–10⁶ Hz) at room temperature. It was found that annealing negatively affected the physical and mechanical properties of samples. But these properties showed improvements before annealing. On the other hand, the permittivity increased with the increase of ZnO contents, annealing temperature and annealing time. For instance, the non-annealed samples with 5 wt.% ZnO showed a decrease in the amount of water absorption, an increase in the modulus of rupture from 66 to 74.69 N mm⁻² and improvements of the dielectric properties. Such samples may be suitable for manufacturing the electrical ceramic capacitors.

Keywords: Ceramic bodies, gahnite phase, modulus of rupture, dielectric properties, influence of ZnO
1. INTRODUCTION

Electrical ceramic bodies have been widely used in transportation and distribution of electricity due to their useful electrical insulating properties. They have been used in insulating electrical lines from the support structure. Further, they have good mechanical properties which could be retained for more than 30 years. To manufacture such materials, firing processes are usually applied at temperatures higher than 1300°C. Usually, the ceramic sintering temperature is reduced by using different flux-forming additives. In this study, natural alkali alumino-silicates (feldspar, pegmatite, perlite, nepheline syenite, etc.) or carbonates of alkali-earth metals are used. For instance, zinc oxide (ZnO) has been used as a strong co-flux in whiteware production. ZnO is one of the major components in commercial glazes for sanitary ware and tiles. Adding it to ceramic bodies even at small proportions results in development of zinc aluminates (gahnite phase, ZnAl$_2$O$_4$) which is a member of the spinel family used as a catalyst, glazing layers for floor tiles and dental applications.

Several properties of ZnAl$_2$O$_4$ have been studied using different computational methods: cation distribution, structure, vibrational spectra, electronic structure, mechanical properties and phonon spectra. In our previous work, the electrical resistivity was found to be increased to 4.4 × 10$^{12}$ Ohm upon adding 4 wt.% ZnO to the aluminous bodies. In this paper, the physical and dielectric properties of ceramic bodies prepared from the Egyptian raw materials with and without adding ZnO were investigated. The dielectric measurements were examined by means of dielectric spectroscopy in the frequency range (10$^{-1}$–10$^6$ Hz) at room temperature.

2. EXPERIMENTAL

The starting Egyptian raw materials were beneficiated Tieh clay (Sinai), Abou Seberia clays near Aswan, nepheline concentrate (product of the beneficiation process of nepheline syenite rock from Abou Krug area in the Eastern Desert) and alumina ($\alpha$-Al$_2$O$_3$). Their chemical compositions are listed in Table 1. ZnO, which was obtained chemically from the pure ZnCO$_3$, was added to the batches as 0, 3, and 5 wt.% as listed in Table 2. Three different mixtures were produced. Each mixture was ball-milled for 2 h in porcelain jar with a purified water medium, then passed through a 200 mesh sieve and dried in an oven at 110°C for 24 h.
Table 1: Chemical analysis and the calculated mineralogical compositions of the raw materials in wt.%.

<table>
<thead>
<tr>
<th>Oxide constitution</th>
<th>Alumina (α-Al₂O₃)</th>
<th>Tiej clay</th>
<th>Abou Seberia clay</th>
<th>Nepheline concentrate</th>
</tr>
</thead>
<tbody>
<tr>
<td>SiO₂</td>
<td>0.12</td>
<td>47.27</td>
<td>67.67</td>
<td>60.02</td>
</tr>
<tr>
<td>Al₂O₃</td>
<td>99.50</td>
<td>35.98</td>
<td>20.95</td>
<td>23.01</td>
</tr>
<tr>
<td>Fe₂O₃</td>
<td>–</td>
<td>0.60</td>
<td>1.40</td>
<td>0.46</td>
</tr>
<tr>
<td>TiO₂</td>
<td>–</td>
<td>2.62</td>
<td>2.00</td>
<td>0.01</td>
</tr>
<tr>
<td>CaO</td>
<td>–</td>
<td>0.07</td>
<td>0.08</td>
<td>0.27</td>
</tr>
<tr>
<td>MgO</td>
<td>–</td>
<td>0.15</td>
<td>0.14</td>
<td>0.01</td>
</tr>
<tr>
<td>K₂O</td>
<td>–</td>
<td>0.06</td>
<td>0.28</td>
<td>6.32</td>
</tr>
<tr>
<td>Na₂O</td>
<td>0.10</td>
<td>0.039</td>
<td>–</td>
<td>9.69</td>
</tr>
<tr>
<td>P₂O₅</td>
<td>–</td>
<td>0.31</td>
<td>0.03</td>
<td>–</td>
</tr>
<tr>
<td>L.O.I</td>
<td>0.26</td>
<td>13.72</td>
<td>7.98</td>
<td>1.09</td>
</tr>
<tr>
<td>Total</td>
<td>99.98</td>
<td>100.80</td>
<td>100.53</td>
<td>100.88</td>
</tr>
</tbody>
</table>

Table 2: Patch compositions of the ceramic bodies.

<table>
<thead>
<tr>
<th>Samples</th>
<th>Patch compositions (wt.%)</th>
<th>Abou Seberia clay</th>
<th>ZnO</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Tiej clay</td>
<td>Alumina (α-Al₂O₃)</td>
<td></td>
</tr>
<tr>
<td>ZN0</td>
<td>40</td>
<td>30</td>
<td>20</td>
</tr>
<tr>
<td>ZN3</td>
<td>40</td>
<td>30</td>
<td>20</td>
</tr>
<tr>
<td>ZN5</td>
<td>40</td>
<td>30</td>
<td>20</td>
</tr>
</tbody>
</table>

For the dielectric measurements, the dried powders were compacted and pressed (under pressure of 40 MPa) into discs with 1 cm in diameter and 0.3 cm in thickness. The specimens were dried at 110°C and then fired between 1150°C and 1300°C. The firing schedule comprised heating; soaking at maximum temperature for 1 h and cooling to room temperature in 2 h. Three batches were produced and denoted in the text as ZN0, ZN3 and ZN5. Another firing regime was used to anneal the specimens at 1,175°C and 1,200°C and cooling to room temperature in the furnace with two soaking times: 2 and 4 h. Additional two batches were also produced and denoted in the text as ZNA3 and ZNA5, where A reveals to the samples after annealing.

The dielectric measurements were carried out by means of high-resolution impedance analyser spectrometer (Schlumberger Solartron 1260) provided with
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an electrometer amplifier and measuring cell to measure the dielectric properties. The output parameters are the capacitance \( C(\omega) \) and the resistance \( R(\omega) \), where \( \omega \) is the angular frequency. The complex dielectric permittivity \( \varepsilon' (\omega) \) was calculated in terms of the two parameters as follows:

\[
\varepsilon' (\omega) = \varepsilon' - i\varepsilon^* = \frac{C(\omega)d}{\varepsilon_o A} - i\frac{R(\omega)d}{\omega R(\omega)\varepsilon_o A}
\]

where \( \varepsilon' \) and \( \varepsilon^* \) are the real (permittivity) and imaginary part (dielectric loss) of the complex dielectric permittivity. The sample thickness is \( d \), the cross sectional area is \( A \), the angular frequency is \( \nu = 2\pi f \). The vacuum permittivity is \( \varepsilon_o = 8.85 \times 10^{-12} \text{ F/m} \). Electrical resistivity \( (\rho) \) can be calculated as a function of \( \omega \) and \( \varepsilon^* \) as follows:

\[
\rho = \frac{1}{\omega\varepsilon_o\varepsilon^*}
\]

For the physical measurements, the bulk density and water absorption were determined using the Archimedes method. The measurements were carried on the ceramic bodies with the same dimensions and conditions mentioned above. For the mechanical measurements, bars with dimension \( 1 \times 1 \times 7 \text{ cm} \) were also processed under the same conditions and fired at selected maturing temperatures to measure the modulus of rupture (MOR) by three point method using an Instron Machine type 1128 Universal Testing.

For the crystallographic studies, the crystalline phases developed in the specimens were identified via x-ray diffractometry (XRD) with CuK\( \alpha \) target while their contents were quantified by measuring the area of the strongest diffraction peak of each phase: \( d_{113} \) (alumina), \( d_{111} \) (cristobalite) and \( d_{311} \) (gahnite). For the microstructure studies, the specimens were examined using Phlips SEM (model XL30), attached with an EDX unit for microanalysis. Specimens were mechanically polished, chemically etched by 20 % hydrofluoric acid solution for 30 s, thoroughly washed, dried and gold sputtered.

3. RESULTS AND DISCUSSION

3.1 X-ray Diffraction Analyses

Figure 1 shows x-ray diffraction patterns of the ceramic bodies. The main crystalline phases and their intensities are listed in Table 3. They are alumina, mullite, cristobalite, ZnAl\(_2\)O\(_4\) (gahnite) and unreacted quartz. It is evident that the
Intensity of these phases is greatly affected by amount of ZnO, annealing time and maximum firing temperature.

![XRD pattern](image)

**Figure 1:** XRD pattern for pure ceramic bodies and ZnO-doped bodies.

**Table 3:** Intensity of crystalline phases developed at pure samples and with ZnO addition.

<table>
<thead>
<tr>
<th>Samples</th>
<th>Intensity (%)</th>
<th>Before annealing</th>
<th>After annealing</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Mullite</td>
<td>Quartz</td>
<td>Cristobalite</td>
</tr>
<tr>
<td>ZN01175/1h</td>
<td>17.1</td>
<td>14.3</td>
<td>9.0 (100)</td>
</tr>
<tr>
<td>ZN31200/1h</td>
<td>10.3</td>
<td>10.6</td>
<td>19.4 (100)</td>
</tr>
<tr>
<td>ZN51250/1h</td>
<td>–</td>
<td>10.7</td>
<td>19.2 (100)</td>
</tr>
<tr>
<td>ZNA31175/4h</td>
<td>6.9</td>
<td>8.3</td>
<td>7.0(100)</td>
</tr>
<tr>
<td>ZNA51200/2h</td>
<td>–</td>
<td>9.7</td>
<td>7.7(100)</td>
</tr>
</tbody>
</table>

Pure sample (ZN0) shows relatively higher intensity of alumina, mullite and unreacted quartz when fired at 1175°C for 1 h. Upon adding ZnO with 3 and 5 wt.% ZnO, more liquid glassy phase content developed that favoured the dissolution of primary mullite formed from clay after firing at 1200°C and 1250°C in ZN3 and ZN5, respectively. The viscosity of such glassy phase is low enough to allow
diffusion of $\text{Zn}^{2+}$, $\text{Al}^{3+}$ and $\text{Si}^{2+}$ ions that participated in crystallising $\text{ZnAl}_2\text{O}_4$ solid solution on cooling leaving a glass rich in silica. Similar results were reported by several authors.\textsuperscript{13,14} The annealed bodies at 1175/4h for ZNA3 and at 1200/2h for ZNA5 lead to small quantity of unreacted quartz due to the partially conversion of $\text{SiO}_2$ into cristobalite.

### 3.2 Morphological Analysis

Figure 2 shows the scanning electron micrographs of the fired bodies before and after annealing. As evident from the figure, the bodies are characterised by dense but inhomogeneous crystalline microstructure containing extensively interlocking of many crystals embedded in a glassy matrix. A quartz grain seems to be under transformation from quartz to cristobalite and very small mullite crystals are observed as needle grains. Inside the glassy phase, an abundant number of fine crystals are revealed. For these bodies we observed through the EDX analyses that the fine crystals were composed of $\text{ZnO}$ and $\text{Al}_2\text{O}_3$, the related figure is not presented in this paper. Since the gahnite is the only binary compound in $\text{ZnO}$-$\text{Al}_2\text{O}_3$ phase diagram,\textsuperscript{15} the analysed crystal in Rosita shape must be gahnite. This in turns supports our assumption that the crystallised gahnite is formed from the feldspar melt and $\text{ZnO}$ dissolution during heating to the sintering temperature.
3.3 Physical Properties

Figure 3 shows the variation of the bulk density (BD) and water absorption (WA) with sintering temperature for free and ZnO-ceramic bodies. The free zinc oxide bodies (ZN0) fired at 1175°C for 1 h have the bulk density values of 2.57 g cm⁻³ and the water absorption values of 0.74%. For the bodies with 3 wt.% ZnO (ZN3) and 5 wt.% ZnO (ZN5), the maturing temperature increases from 1175°C /1 h to...
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1200°C and from 1175°C /1 h to 1250°C, respectively. Besides, ZN3 bodies show an increase in BD up to 2.59 g cm\(^{-3}\) with the decrease of WA (0.1%). For ZN5 bodies, BD shows relatively lower values (2.56 g/cm\(^3\)) and a slightly increase of WA (0.23%) after firing for 1 h at 1250°C.

Figure 3: Water absorption and bulk density with sintering temperatures (a); and after annealing time (b) for free zinc oxide sample fired at 1175°C (ZN0), sample with 3 wt.% ZnO (ZN3) and sample with 5 wt.% ZnO.

The effect of the second firing regime on densification in terms of BD and WA of the fired bodies is examined as listed in Table 4. It clearly shows that both ZNA3 and ZNA5 show lower bulk densities of 2.51 and 2.55 g cm\(^{-3}\) after annealing for 2 and 4 h at 1175°C and 1200°C, respectively. Further, the annealing has no significant effect on the densification properties of the fired bodies in comparison with those fired without annealing. Therefore, one can conclude that the bulk density of the
ceramic bodies are affected by ZnO concentration, porosity percentage and firing regime.

Table 4: Physico-mechanical properties of zinc ceramic bodies at sintered temperature (before and after annealing).

<table>
<thead>
<tr>
<th>Samples</th>
<th>Bulk density (g cm(^{-3}))</th>
<th>Water absorption (%)</th>
<th>Modulus of rupture (N mm(^{-2}))</th>
</tr>
</thead>
<tbody>
<tr>
<td>ZN01175/1h</td>
<td>2.57</td>
<td>0.74</td>
<td>66.00</td>
</tr>
<tr>
<td>ZN31200/1h</td>
<td>2.59</td>
<td>0.10</td>
<td>68.42</td>
</tr>
<tr>
<td>ZN51250/1h</td>
<td>2.56</td>
<td>0.23</td>
<td>74.69</td>
</tr>
<tr>
<td>ZNA31175/4h</td>
<td>2.51</td>
<td>1.48</td>
<td>44.44</td>
</tr>
<tr>
<td>ZNA51200/2h</td>
<td>2.55</td>
<td>0.53</td>
<td>51.17</td>
</tr>
</tbody>
</table>

3.4 Mechanical Properties

Modulus of rupture (MOR) values in its dependence of firing temperature, annealing and ZnO content are listed in Table 4. For bodies containing 5 wt.% of ZnO and before annealing (ZN5), MOR exhibits an increase and attains to the maximum values (74.69 N mm\(^{-2}\)), leading to the improvements of their mechanical properties. One can attribute such improvements to the development of gahnite phase. However, after annealing, for the bodies denoted as ZNA5, MOR shows a moderate decrease from 74.69 to 51.17 N mm\(^{-2}\) whereas the water absorption shows a considerable increase from 0.23% to 0.53%. Accordingly, the main factor that greatly affected MOR values is the variation of the crystalline phases. These observations agree with the three main theories proposed to explain the mechanical properties of porcelain\(^{13}\) which consider that the crystalline phases present and dispersed in the vitreous phase are the ruling factor influencing the mechanical properties.

3.5 Dielectric Properties

The frequency dependence of the permittivity (\(\varepsilon'\)), dielectric loss (\(\varepsilon''\)) and ac resistivity (\(\rho\)) of all ceramic bodies before and after annealing is shown in Figure 4. Here, both \(\varepsilon'\) and \(\varepsilon''\) increase monotonically with the frequency decrease. This behaviour can be described by the Debye dispersion relations.\(^{16}\) The permittivity decrease is in fact associated to a decrease in the total polarisation. The total polarisations arises from the contribution of four kinds of polarisation, namely electronic, ionic, rotation or orientation, and space charge polarisation.\(^{17}\) The relatively high values seen in \(\varepsilon'\) at low frequencies (<10\(^3\) Hz) are probably due to space charge polarisation.\(^{18-21}\) Space charge polarisation is caused by the mobile
Influence of ZnO charges carriers which are present at the interfaces. These mobile charges are impeded by interfaces, because they are not discharged at an electrode, or because they are trapped in the material defects (vacancies, micropores, etc.).

When an external electric field is applied, the space charge moves and then becomes trapped by the ceramic defects, causing changes in the positive and negative charges distribution at the interfaces. Hence, a lot of dipole moments are formed (space charge polarisation). Therefore, the interfacial polarisation is the main factor that affects permittivity of any heterogeneous material like ceramic materials. In the high frequency region (>10^3 Hz), ε' shows a plateau-like behaviour indicating dipolar or orientation polarisation dependence. Here, the dipole would be unable to follow the rapid change in the electric field frequency, hence the orientation polarisation stops and ε' becomes constant.

Figure 4: The frequency dependence of permittivity (ε'), dielectric loss (ε'') and resistivity (ρ) for ceramic bodies; free zinc oxide sample fired at 1175°C (ZN0), sample with 3 wt.% ZnO before annealing (ZN3), sample with 5 wt.% ZnO before annealing (ZN5), sample with 3 wt.% ZnO after annealing at 1175°C/4 h (ZNA3), and sample with 5 wt.% ZnO after annealing at 1,250°C/2 h (ZNA5).
The orientation polarisation may occur in the ceramic bodies when two or more equivalent positions for an ion are present. Upon applying an electric field, ions such as Zn\(^{2+}\), Al\(^{3+}\) and Si\(^{2+}\) can be exchanged in positions with the possible vacancies by a simple jump of the cation to the nearest vacancy. Therefore, orientation polarisation is also known as ion jump polarisation. On the other hand, the ceramic dielectric loss (\(\varepsilon''\)) shows a decrease at two different rates indicating two different relaxation processes. Further, the relatively high values seen in \(\varepsilon''\) at low frequencies could be related to contribution of DC conductivity (reciprocal of resistivity).

The ceramic permittivity values can also be correlated with ZnO contents and annealing temperature. For instance, sample with the higher contents of ZnO and annealed at 1200°C/2 h (ZNA5) exhibits the maximum permittivity (40 at \(\nu = 0.1\) Hz). This is probably attributed to the mobility increase of dipoles or/and charge carriers due to the development of more liquid phase content upon adding ZnO as mentioned above. This leads to a decrease in the ceramic resistivity as shown in Figure 4(c). Therefore, the substitution of Zn\(^{2+}\) leads to an increase in the conduction ions density and hence lowering the ceramic resistivity. For such a case, the metal oxides or mineralisers become dissolved partially into the glassy phase causing a resistivity decrease.

4. CONCLUSION

Physical, mechanical and dielectric properties of the ceramic bodies containing zinc oxide and firing at high temperatures between 1150°C and 1300°C were improved due to developments of the gahnite phase (ZnAl\(_2\)O\(_4\)). For instance, the ceramic bodies with 5 wt.% ZnO fired at 1250°C for 1 h were characterised by the maximum modulus of rupture (74.69 N mm\(^{-2}\)), high permittivity (~20) and a continuous decrease in dielectric loss. These features revealed to the possibility of use such bodies as electrical capacitors or as a good replacement of SiO\(_2\) in high power devices. The interesting features given for such ceramics may make them technologically important and competitive to other alternative electronic devices, not only due to the low cost but also due to easy processing and the availability of raw materials.

5. ACKNOWLEDGEMENTS

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6. REFERENCES


